²⁰⁹Bi(⁴⁰Ar,3n) (4.4 s) **2010An08**

Type Author Citation Literature Cutoff Date

Full Evaluation C. D. Nesaraja NDS 198,449 (2024) 31-Jul-2022

2010An08: 246 Md was produced via 209 Bi(40 Ar,3n) at the velocity filter SHIP at GSI. E(40 Ar)=187 and 198 MeV from the UNILAC bombarded a 0.450 μ g/cm² metallic 209 Bi target. Measurements were performed with an array of position-sensitive Si detectors and a Ge clover detector consisting of four Ge crystals.

Measured: E γ , I γ , ce, E α , $\alpha\gamma$ coin, α (ce) coin, (recoil) α , (recoil) $\alpha\gamma$ coin, half-lives, α decay branching ratios. A ²⁴⁶Md isomer with 4.4 s half-life was identified in this work.

²⁴⁶Md Levels

E(level)	$T_{1/2}$	Comments
0+x	0.9 s 2	$\%\alpha=100; \%SF=?; \%\varepsilon+\%\beta^{+}=?$
		T _{1/2} : From 2010An08. Others: 0.75 s 18 (2006An13), 1.0 s 4 (1996Ni09),1.0 s 4 (1994HoZW).
		Spontaneous fission (SF) was observed decaying with $T_{1/2}=1.0 \text{ s} +10-3$. Part of this decay has been assigned
		to electron-capture delayed spontaneous fission (ε -SF) (2010An08).
0+y	4.4 s 8	$%ε+%β^+>77; %α<23 (2010An08)$
		T _{1/2} : From 2010An08.
		$E\alpha$ =8178 keV 10, $E\gamma$ =252.0- and 279.0-keV were observed following α decay of 246 Md(4.4 s) to 242 Es.
		Possible & delayed SF decay (%&SF>10) from ²⁴⁶ Md(4.4 s) (2010An08). Other: 1996Ni09.